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Client/Matter: 081468-0307456

IN THE CLAIMS:

This listing of claims will replace all prior versions, and listings, of claims in the

application:

1. (Currently Amended) A lithographic apparatus comprising:

a radiation source that produces EUV radiation;

an illumination system that provides a beam of said EUV radiation produced by said

radiation source;

a support structure that supports a patterning structure, the patterning structure

configured to impart the beam of radiation with a pattern in its cross-section;

a substrate support that supports a substrate; and

a projection system that projects the patterned beam onto a target portion of the

substrate,

wherein said radiation source comprises a debris-mitigation system that mitigates

debris particles which are formed during production of EUV radiation, the debris-mitigation

system configured to provide additional particles for interacting with the debris particles, and

wherein the debris-mitigation system comprises a plurality of electrodes that cause a

discharge of particles when a suitable voltage is applied so that the additional particles are

generated.

2. (Original) A lithographic apparatus according to claim 1, wherein the debris-

mitigation system is arranged to provide a flow of the additional particles.

3. (Original) A lithographic apparatus according to claim 2, wherein the debris-

mitigation system is arranged to provide the flow into a direction which is substantially

different from a downstream direction of a radiation beam.

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4. (Original) A lithographic apparatus according to claim 2, wherein the debris-

mitigation system is arranged to provide the flow of additional particles that substantially

cross a radiation beam.

5. (Currently Amended) A lithographic apparatus according to claim 2, further

comprising a collector for collecting EUV radiation that originates from the radiation source,

wherein the debris-mitigation system is further arranged to provide a the flow of additional

particles such that the additional particles flow substantially away from the collector.

6. (Original) A lithographic apparatus according to claim 2, wherein the debris-

mitigation system is further arranged to provide a supersonic flow of additional particles.

7. (Original) A lithographic apparatus according to claim 1, wherein the

additional particles comprise ionized particles.

8. Canceled.

9. (Currently Amended) A lithographic apparatus according to claim 1, wherein

the debris-mitigation system further comprises a plasma generator that generates the further

additional particles.

10. (Original) A lithographic apparatus according to claim 9, wherein the plasma

generator comprises Radio Frequency induction coils.

11. Canceled.

12. Canceled.

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- 13. (Currently Amended) A lithographic apparatus comprising:
- a radiation source that produces EUV radiation;
- an illumination system that provides a beam of said EUV radiation produced by said radiation source;
- a support structure that supports a patterning structure, the patterning structure configured to impart the beam of radiation with a pattern in its cross-section;
  - a substrate support that supports a substrate;
- a projection system that projects the patterned beam onto a target portion of the substrate; and
- a particle generator that generates additional particles for interacting with debris particles, wherein said particle generator comprises an outlet and a pump.
  - 14. Canceled.
- 15. (Currently Amended) A lithographic apparatus according to claim 13, wherein said particle generator <u>further</u> comprises a plurality of electrodes.
  - 16. Canceled.
- 17. (Currently Amended) A lithographic apparatus according to claim 1613, wherein said pump comprises an ion getter pump.
- 18. (Currently Amended) A lithographic apparatus according to claim 16 13, wherein said outlet and said pump are arranged to provide a flow of the additional particles is in a direction substantially different from a downstream direction of the beam of radiation.
- 19. (Original) A lithographic apparatus according to claim 13, wherein said particle generator forms part of said radiation source.

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20. Canceled.

- 21. (New) A lithographic apparatus according to claim 13, wherein the particle generator is arranged to provide a supersonic flow of the additional particles.
  - 22. (New) A lithographic apparatus comprising:

a radiation source that produces EUV radiation;

an illumination system that provides a beam of said EUV radiation produced by said radiation source;

a support structure that supports a patterning structure, the patterning structure configured to impart the beam of radiation with a pattern in its cross-section;

a substrate support that supports a substrate; and

a projection system that projects the patterned beam onto a target portion of the substrate,

wherein said radiation source comprises a debris-mitigation system that mitigates debris particles which are formed during production of EUV radiation, the debris-mitigation system configured to provide additional particles for interacting with the debris particles, and wherein the debris-mitigation system comprises a plasma generator configured to provide ionized particles.

- 23. (New) A lithographic apparatus according to claim 22, wherein the plasma generator comprises Radio Frequency induction coils.
  - 24. (New) A lithographic apparatus comprising:

a radiation source that produces EUV radiation;

an illumination system that provides a beam of said EUV radiation produced by said radiation source;

a support structure that supports a patterning structure, the patterning structure

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configured to impart the beam of radiation with a pattern in its cross-section;

a substrate support that supports a substrate; and

a projection system that projects the patterned beam onto a target portion of the substrate,

wherein said radiation source comprises a debris-mitigation system that mitigates debris particles which are formed during production of EUV radiation, the debris-mitigation system configured to provide a supersonic flow of additional particles for interacting with the debris particles.

## 25. (New) A lithographic apparatus comprising:

a radiation source that produces EUV radiation;

an illumination system that provides a beam of said EUV radiation produced by said radiation source;

a support structure that supports a patterning structure, the patterning structure configured to impart the beam of radiation with a pattern in its cross-section;

a substrate support that supports a substrate;

a projection system that projects the patterned beam onto a target portion of the substrate; and

a particle generator that generates additional particles for interacting with debris particles, wherein the particle generator comprises a plurality of electrodes.